TOSHIBA

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74AC164P,TC74AC164F,TC74AC164FN,TC74AC164FT

8-Bit Shift Register (S-IN, P-OUT)

The TC74AC164 is an advanced high speed CMOS 8-BIT SERIAL-IN PARALLEL-OUT SHIFT REGISTER fabricated with silicon gate and double-layer metal wiring C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

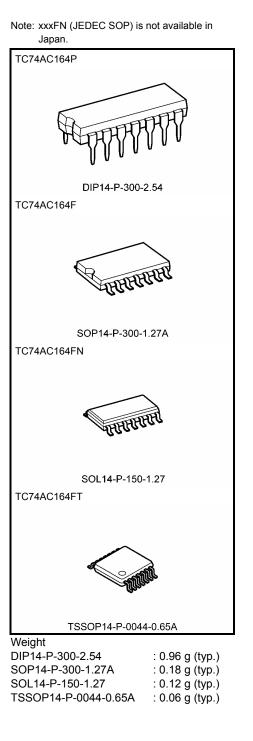
It consists of a serial-in, parallel-out 8-bit shift register with a CLOCK input and an overriding $\overline{\text{CLEAR}}$ input.

Two serial data inputs (A, B) are provided so that one may be used as a data enable.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

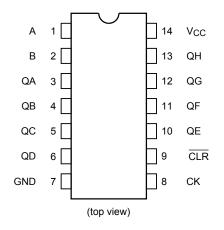
Features

- High speed: $f_{max} = 170 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: I_{CC} = 8 μA (max) at Ta = 25°C
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Symmetrical output impedance: |IOH| = IOL = 24 mA (min) Capability of driving 50 Ω transmission lines.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: VCC (opr) = 2 V to 5.5 V
- Pin and function compatible with 74F164

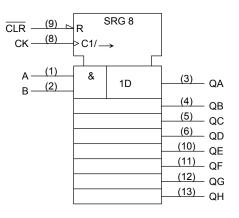


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Pin Assignment



IEC Logic Symbol



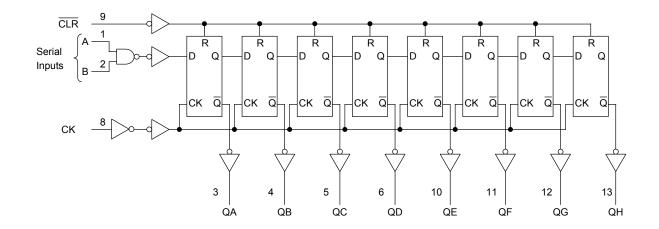
Truth Table

	Inp	uts		Outputs					
CLR	СК	Serial In		~	QB				
		А	В	QA	QD		QH		
L	Х	Х	Х	L	L		L		
Н		Х	Х	No Change					
Н		L	Х	L	QA _n		QGn		
Н		Х	L	L	QAn		QGn		
Н		Н	Н	Н	QAn		QGn		

X: Don't care

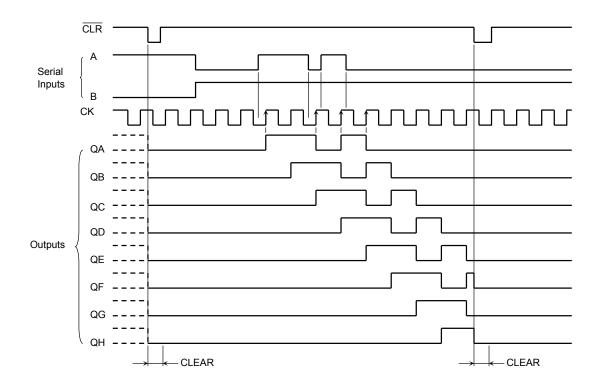
QAn to QGn: The level of QA to QG, respectively, before the most recent positive edge of the clock.

System Diagram



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Timing Chart



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5 to 7.0	V
DC input voltage	VIN	-0.5 to V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Input diode current	lıк	±20	mA
Output diode current	IOK	±50	mA
DC output current	lout	±50	mA
DC V _{CC} /ground current	ICC	±200	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T _{stg}	−65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = −40°C to 65°C. From Ta = 65°C to 85°C a derating factor of −10 mW/°C should be applied up to 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	2.0 to 5.5	V	
Input voltage	V _{IN}	0 to V _{CC}	V	
Output voltage	V _{OUT}	0 to V _{CC}	V	
Operating temperature	T _{opr}	-40 to 85	°C	
Input rise and fall time	dt/dV	0 to 100 (V _{CC} = 3.3 ± 0.3 V)	ns/V	
	uvuv	0 to 20 (V _{CC} = 5 \pm 0.5 V)	ns/v	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition				Га = 25°С)	Ta = −40 to 85°C		Unit		
Characteristics	Gymbol				V _{CC} (V)	Min	Тур.	Max	Min	Max		
					2.0	1.50	_	_	1.50	_		
High-level input voltage	VIH		_		3.0	2.10	_	—	2.10	_	V	
				5.5	3.85	—	—	3.85	—			
					2.0	_	—	0.50	_	0.50		
Low-level input voltage	V _{IL}		_		3.0	—	—	0.90	—	0.90	V	
ő					5.5	-	—	1.65	-	1.65		
	V _{OH}				2.0	1.9	2.0	_	1.9	—		
		V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	3.0	2.9	3.0	—	2.9	—	v		
High-level output					4.5	4.4	4.5	_	4.4		-	
voltage			I _{OH} = −4 mA		3.0	2.58	—	—	2.48	—	v	
			I _{OH} = −24 mA		4.5	3.94	—	_	3.80	—		
			I _{OH} = −75 mA	(Note)	5.5	-	—	—	3.85	-		
		V _{IN} = V _{IH} or			2.0	—	0.0	0.1	_	0.1		
	V _{OL}		I _{OL} = 50 μA		3.0	—	0.0	0.1	—	0.1		
Low-level output					4.5	_	0.0	0.1	_	0.1	V	
voltage		VIL	I _{OL} = 12 mA		3.0	—	—	0.36	—	0.44	v	
			I _{OL} = 24 mA		4.5	—	—	0.36	—	0.44		
			I _{OL} = 75 mA	(Note)	5.5	_	_	—	_	1.65		
Input leakage current	lin	V _{IN} = V _C	_C or GND		5.5	_	_	±0.1	_	±1.0	μA	
Quiescent supply current	Icc	V _{IN} = V _C	_C or GND		5.5	_	—	8.0	_	80.0	μA	

Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

Timing Requirements (input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C	Ta = −40 to 85°C	Unit	
	,		V _{CC} (V)	Limit	Limit		
Minimum pulse width	t _{w (L)}		3.3 ± 0.3	9.0	10.0		
(CK)	t _{w (H)}	—	5.0 ± 0.5	5.0	6.0	ns	
Minimum pulse width			3.3 ± 0.3	9.0	10.0		
(CLR)	^t w (L)	—	5.0 ± 0.5	5.0	6.0	ns	
	ts	_	3.3 ± 0.3	7.0	7.0	ns	
Minimum set-up time			5.0 ± 0.5	4.0	4.0		
			3.3 ± 0.3	1.0	1.0		
Minimum hold time	t _h	—	5.0 ± 0.5	1.0	1.0	ns	
Minimum removal time	t _{rem}	_	3.3 ± 0.3	8.5	8.5	ns	
(CLR)			5.0 ± 0.5	5.0	5.0		

AC Characteristics (C_L = 50 pF, R_L = 500 Ω , input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit
	- ,		V _{CC} (V)	Min	Тур.	Max	Min	Max	
Propagation delay time (CK-Q)	t _{pLH} t _{pHL}	_	3.3 ± 0.3 5.0 ± 0.5		9.6 6.6	16.3 9.8	1.0 1.0	18.6 11.2	ns
Propagation delay time (CLR -Q)	tpHL	_	3.3 ± 0.3 5.0 ± 0.5	_	8.0 6.0	15.4 11.0	1.0 1.0	17.5 12.5	ns
Maximum clock frequency	f _{max}	_	3.3 ± 0.3 5.0 ± 0.5	45 85	100 150	_	45 80	_	MHz
Input capacitance	C _{IN}	_		_	5	10	_	10	pF
Power dissipation capacitance	C _{PD}		(Note)	_	110	—	_	_	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

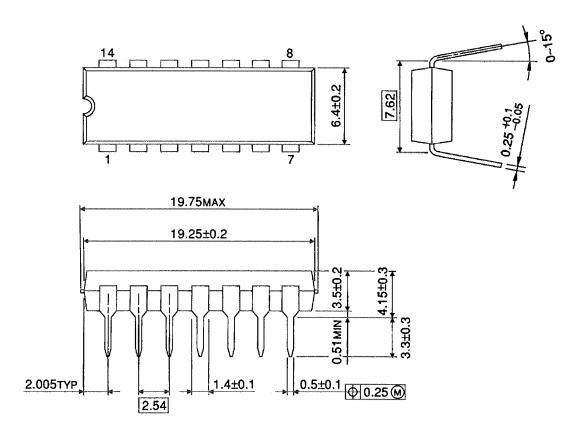
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Package Dimensions

DIP14-P-300-2.54

Unit : mm



Weight: 0.96 g (typ.)

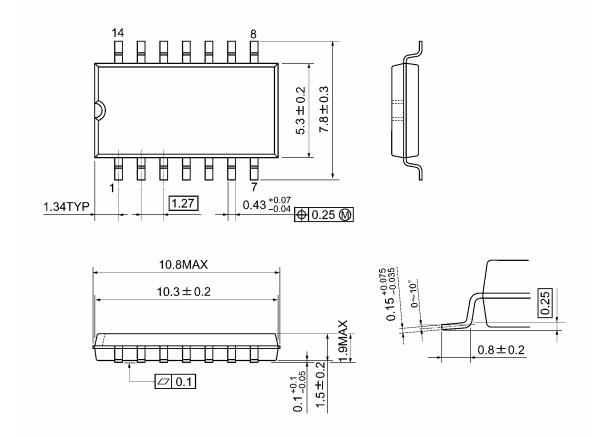
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Package Dimensions

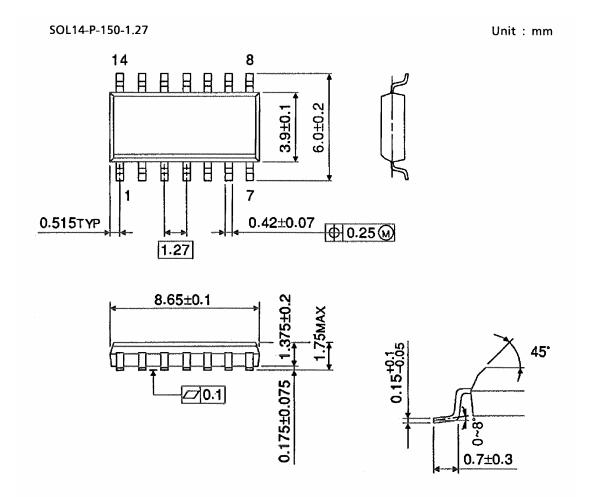
SOP14-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

Package Dimensions (Note)



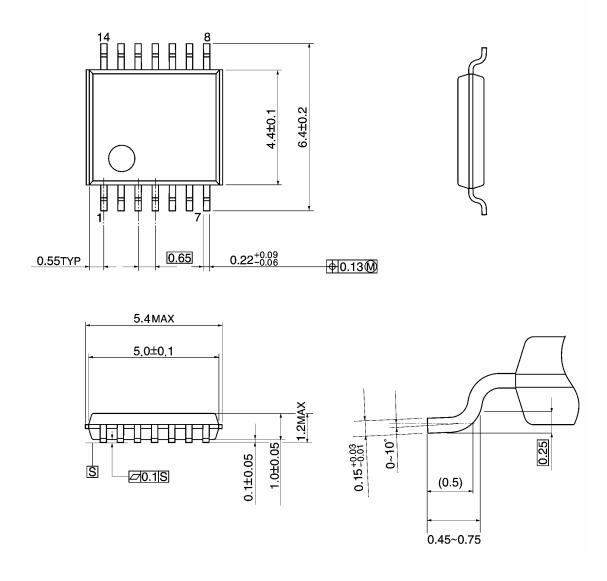
Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Package Dimensions

TSSOP14-P-0044-0.65A

Unit: mm



Weight: 0.06 g (typ.)

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20070701-EN GENERAL

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